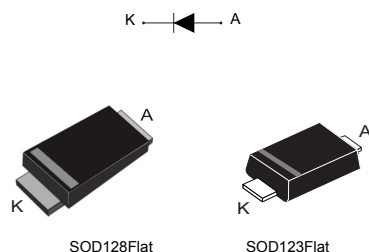


100 V - 1 A power Schottky trench rectifier



Features

- High junction temperature capability
- Low forward voltage drop
- Low recovery charges
- Reduces conduction, reverse and switching losses
- Avalanche tested
- Flat packages
- ECOPACK2 compliant

Applications

- DC/DC converter
- LED lighting
- Flyback topology
- Auxiliary power supply
- Switch mode power supply (SMPS)



Product label



Product status link

[STPST1H100](#)

Description

This 1 A, 100 V rectifier is based on ST trench technology that achieves the best-in-class V_F/I_R trade-off for a given silicon surface.

Integrated in flat and space-saving packages, this STPST1H100 trench rectifier is intended to be used in high frequency miniature switched mode power supplies. It is also an ideal candidate for auxiliary power supply in telecom, server, or smart metering. ST trench rectifiers are adapted to freewheeling, OR-ring or reverse polarity protection applications, and can be the perfect companion device to our transistors, drivers, or ST VIPer products.

Product summary

$I_{F(AV)}$	1 A
V_{RRM}	100 V
T_j (max.)	175 °C
V_F (typ.)	0.580 V

1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			100	V
I _{F(AV)}	Average forward current, δ = 0.5, square wave	SOD123Flat	T _L = 155 °C	1	A
		SOD128Flat	T _L = 155 °C		
I _{FSM}	Surge non repetitive forward current	SOD123Flat	t _p = 10 ms sinusoidal	25	A
		SOD128Flat			
I _{AS}	Single pulse avalanche current ⁽¹⁾	T _j = 25°C, L = 300 μH, V _{DD} = 15 V		2	A
T _{stg}	Storage temperature range			-65 to +175	°C
T _j	Maximum operating junction temperature ⁽²⁾			+175	°C

1. Please refer to [Figure 1](#) and [Figure 2](#) for the unclamped inductive switching test circuit, and waveform.
2. $(dP_{tot}/dT_J) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameter

Symbol	Parameter		Typ. value	Unit
$R_{th(j-l)}$	Junction to lead	SOD123Flat	16	°C/W
		SOD128Flat	15	

For more information, please refer to the following application note:

- [AN5088](#): Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_J = 125\text{ °C}$	$V_R = 70\text{ V}$	-	0.15	0.48	mA
		$T_J = 25\text{ °C}$	$V_R = 100\text{ V}$	-		1.7	μA
		$T_J = 125\text{ °C}$		-	0.3	1	mA
$V_F^{(2)}$	Forward voltage drop	$T_J = 25\text{ °C}$	$I_F = 0.5\text{ A}$	-	0.545	0.610	V
		$T_J = 125\text{ °C}$		-	0.480	0.540	
		$T_J = 25\text{ °C}$	$I_F = 1\text{ A}$	-	0.650	0.725	
		$T_J = 125\text{ °C}$		-	0.580	0.635	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$
2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.445 \times I_{F(AV)} + 0.190 \times I_F^2(RMS)$$

For more information, please refer to the following application notes related to the power losses :

- [AN604](#): Calculation of conduction losses in a power rectifier
- [AN4021](#): Calculation of reverse losses on a power diode

Figure 1. Current and voltage waveforms for avalanche energy test across D.U.T (device under test)

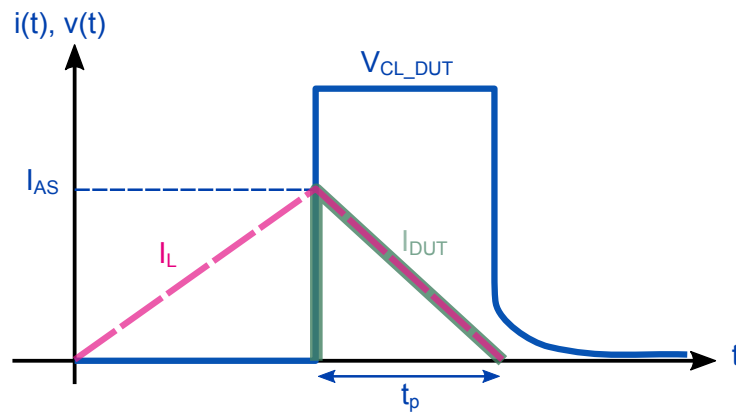
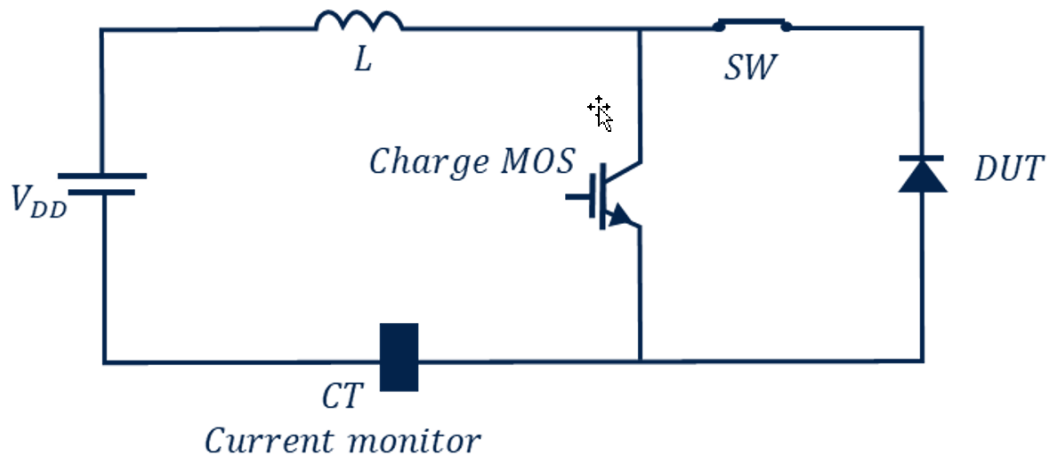


Figure 2. Unclamped Inductive Switching Test circuit



$$E_{AS} = \frac{1}{2} \times L \times I_{AS}^2 \times \left(\frac{V_{CLDUT}}{V_{CLDUT} - V_{DD}} \right) \cong \frac{1}{2} \times L \times I_{AS}^2$$

$$t_p = \left(\frac{L \times I_{AS}}{V_{CLDUT} - V_{DD}} \right)$$

1.1 Characteristics (curves)

Figure 3. Average forward current versus lead temperature ($\delta = 0.5$)

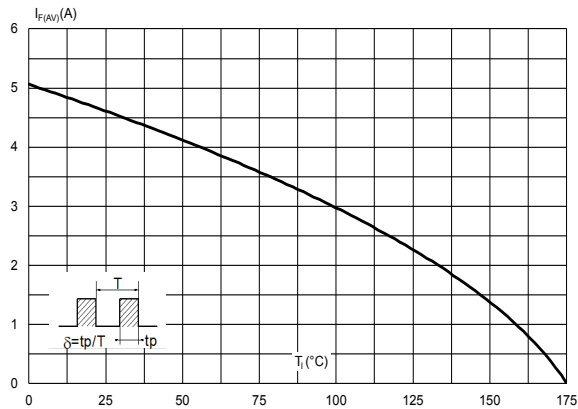


Figure 4. Relative variation of thermal impedance junction to lead versus pulse duration (SOD123Flat)

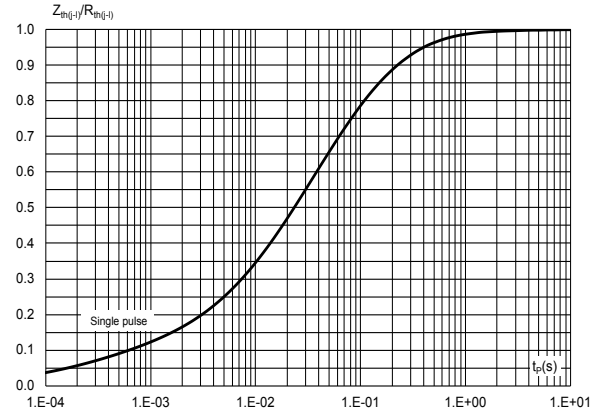


Figure 5. Relative variation of thermal impedance junction to lead versus pulse duration (SOD128Flat)

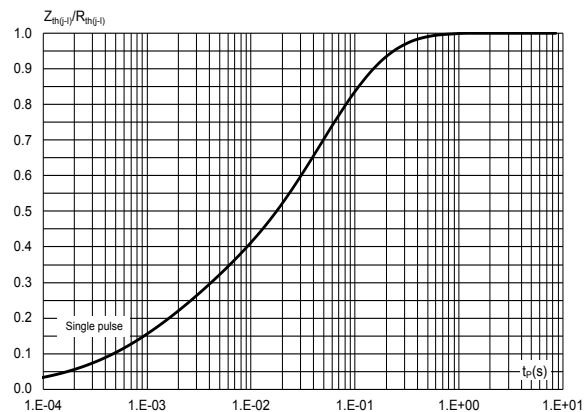


Figure 6. Reverse leakage current versus reverse voltage applied (typical values)

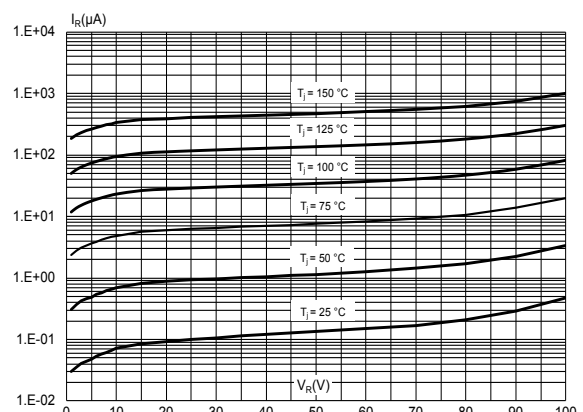


Figure 7. Junction capacitance versus reverse voltage applied (typical values)

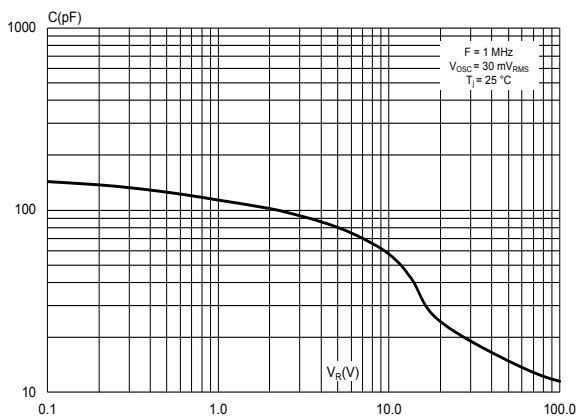


Figure 8. Forward voltage drop versus forward current (typical values)

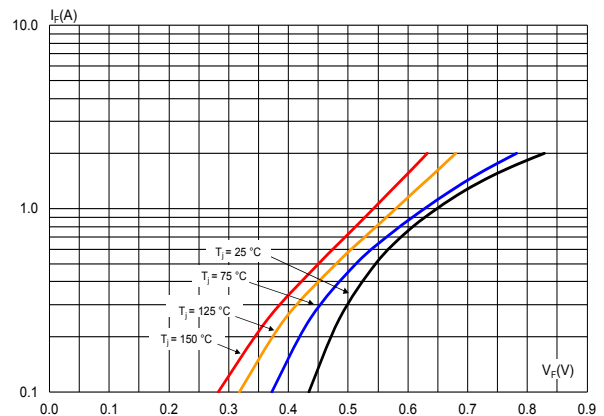


Figure 9. Thermal resistance junction to ambient versus copper surface under each lead (typical values, epoxy printed board FR4, $e_{Cu} = 70 \mu m$)

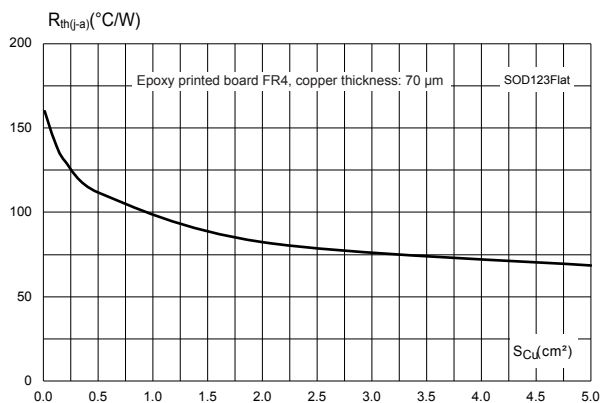
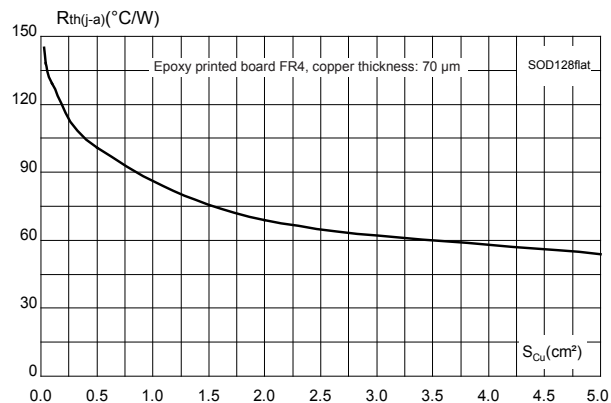


Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (typical values, epoxy printed board FR4, $e_{Cu} = 70 \mu m$)

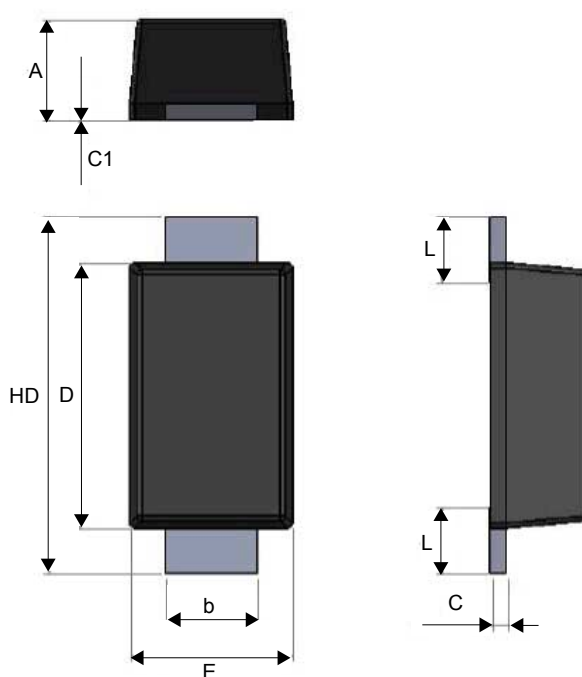


2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 SOD123Flat package information

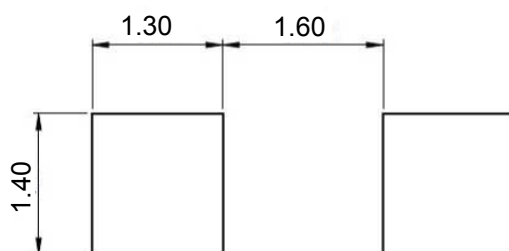
Figure 11. SOD123Flat package outline



Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 4. SOD123Flat package mechanical data

Ref.	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.86	0.98	1.10	0.034	0.038	0.043
b	0.80	0.90	1.00	0.031	0.035	0.039
c	0.08	0.15	0.25	0.003	0.006	0.009
c1	0.00		0.10	0.000		0.004
D	2.50	2.60	2.70	0.098	0.102	0.106
E	1.50	1.60	1.80	0.059	0.063	0.070
HD	3.30	3.50	3.70	0.130	0.137	0.146
L	0.45	0.65	0.85	0.018	0.025	0.033

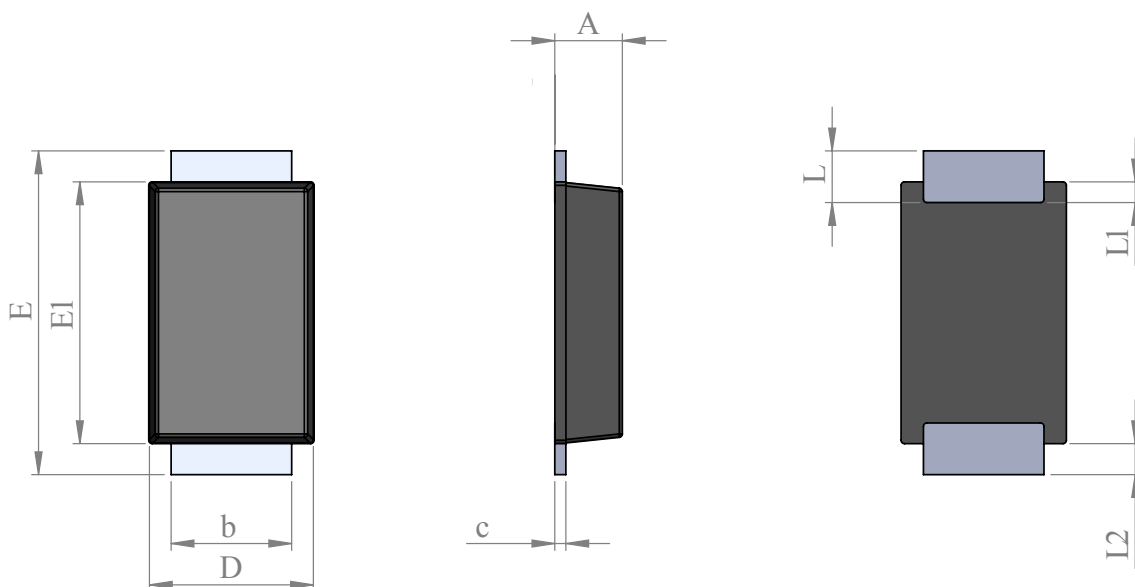
Figure 12. SOD123Flat footprint dimensions (mm)


Note: For package and tape orientation, reel and inner box dimensions and tape outline please check [TN1173](#).

2.2 SOD128Flat package information

- Lead-free package

Figure 13. SOD128Flat package outline

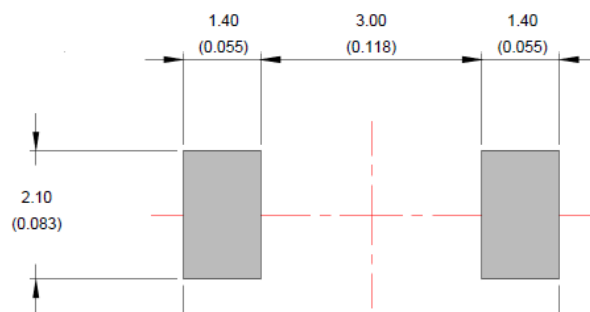


Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 5. SOD128Flat package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.93	1.03	0.037	0.041
b	1.69	1.81	0.067	0.071
c	0.10	0.22	0.004	0.009
D	2.30	2.50	0.091	0.098
E	4.60	4.80	0.181	0.189
E1	3.70	3.90	0.146	0.154
L	0.55	0.85	0.026	0.033
L1	0.30 typ.		0.012 typ.	
L2	0.45 typ.		0.018 typ.	

Figure 14. SOD128Flat footprint in mm (inches)



Note: For package and tape orientation, reel and inner box dimensions and tape outline please check [TN1173](#).

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPST1H100ZF	T01	SOD123 Flat	12.5 mg	3000	Tape and reel
STPST1H100AF	T1H1	SOD128 Flat	26.4 mg	3000	

Revision history

Table 7. Document revision history

Date	Revision	Changes
02-Jan-2023	1	Initial release.
26-May-2023	2	Updated Figure 13 .
21-Jul-2023	3	Updated <i>Features</i> .

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